NX3L1G3157

Low-ohmic single-pole double-throw analog switch

Rev. 08 — 26 April 2010

Product data sheet

1. General description

The NX3L1G3157 is a low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. It has a digital select input (S), two independent inputs/outputs (Y0 and Y1) and a common input/output (Z). Schmitt-trigger action at the digital input makes the circuit tolerant to slower input rise and fall times.

The NX3L1G3157 allows signals with amplitude up to V_{CC} to be transmitted from Z to Y0 or Y1; or from Y0 or Y1 to Z. Its low ON resistance (0.5 Ω) and flatness (0.13 Ω) ensures minimal attenuation and distortion of transmitted signals.

2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance:
 - 1.6 Ω (typical) at $V_{CC} = 1.4 \text{ V}$
 - 1.0 Ω (typical) at $V_{CC} = 1.65 \text{ V}$
 - 0.55 Ω (typical) at V_{CC} = 2.3 V
 - 0.50 Ω (typical) at $V_{CC} = 2.7 \text{ V}$
 - 0.50 Ω (typical) at V_{CC} = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 7500 V
 - ♦ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
 - ◆ IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD78 Class II Level A
- Direct interface with TTL levels at 3.0 V
- Control input accepts voltages above supply voltage
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



Low-ohmic single-pole double-throw analog switch

3. Applications

- Cell phone
- PDA
- Portable media player

4. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
NX3L1G3157GW	−40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363
NX3L1G3157GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886

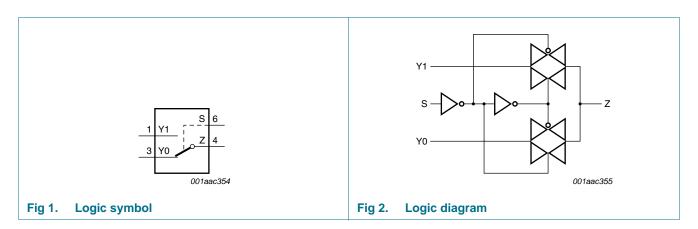
5. Marking

Table 2. Marking codes[1]

Type number	Marking code
NX3L1G3157GW	MJ
NX3L1G3157GM	MJ

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

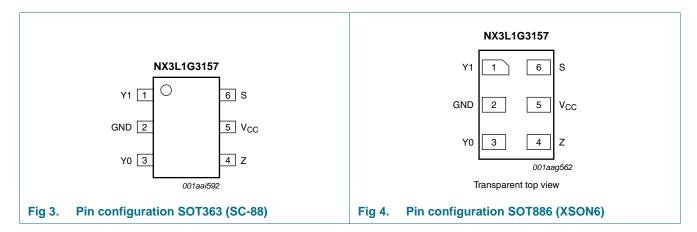
6. Functional diagram



Low-ohmic single-pole double-throw analog switch

7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
Y1	1	independent input or output
GND	2	ground (0 V)
Y0	3	independent input or output
Z	4	common output or input
V _{CC}	5	supply voltage
S	6	select input

8. Functional description

Table 4. Function table [1]

Input S	Channel on
L	Y0
Н	Y1

^[1] H = HIGH voltage level; L = LOW voltage level.

Low-ohmic single-pole double-throw analog switch

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
V_{I}	input voltage	select input S	<u>[1]</u> –0.5	+4.6	V
V_{SW}	switch voltage		<u>[2]</u> –0.5	$V_{CC} + 0.5$	V
I _{IK}	input clamping current	$V_1 < -0.5 \text{ V}$	-50	-	mΑ
I _{SK}	switch clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±50	mΑ
I_{SW}	switch current	$V_{SW} > -0.5 \text{ V or } V_{SW} < V_{CC} + 0.5 \text{ V};$ source or sink current	-	±350	mA
		V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T _{stg}	storage temperature		–65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[3] _	250	mW

^[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		1.4	4.3	V
VI	input voltage	select input S	0	4.3	V
V _{SW}	switch voltage		<u>[1]</u> 0	V_{CC}	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$	[2] -	200	ns/V

^[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

^[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

^[3] For SC-88 package: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K. For XSON6 package: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

^[2] Applies to control signal levels.

Low-ohmic single-pole double-throw analog switch

11. Static characteristics

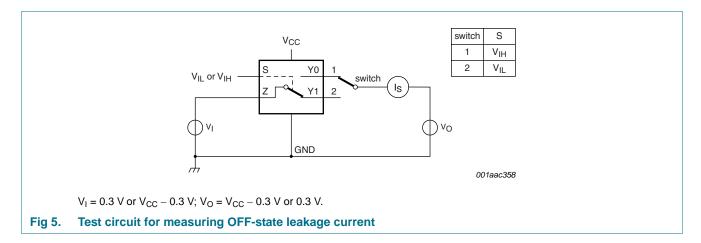
Table 7. Static characteristics

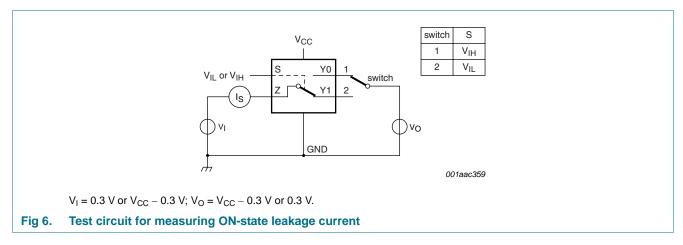
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol Parameter		Conditions	T _{amb} = 25 °C			T_{amb} = -40 °C to +125 °C			Unit
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V_{IH}	HIGH-level	V _{CC} = 1.4 V to 1.95 V	$0.65V_{CC}$	-	-	$0.65V_{CC}$	-	-	V
	input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7	-	-	1.7	-	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	-	V
		V _{CC} = 3.6 V to 4.3 V	$0.7V_{CC}$	-	-	$0.7V_{CC}$	-	-	V
V_{IL}	LOW-level	V _{CC} = 1.4 V to 1.95 V	-	-	$0.35V_{\rm CC}$	-	$0.35V_{\rm CC}$	$0.35V_{\rm CC}$	V
	input voltage	V _{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	0.7	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	0.8	V
		V _{CC} = 3.6 V to 4.3 V	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	$0.3V_{CC}$	V
I _I	input leakage current	select input S; $V_I = GND \text{ to } 4.3 \text{ V};$ $V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$	-	-	-	-	±0.5	±1	μА
I _{S(OFF)}	OFF-state leakage	Y0 and Y1 port; see <u>Figure 5</u>							
	current	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±500	nA
I _{S(ON)}	ON-state	Z port; see Figure 6							
	leakage current	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
	current	$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±500	nA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC}							
		V _{CC} = 3.6 V	-	-	100	-	690	6000	nA
		V _{CC} = 4.3 V	-	-	150	-	800	7000	nA
Cı	input capacitance		-	1.0	-	-	-	-	pF
$C_{\text{S(OFF)}}$	OFF-state capacitance		-	35	-	-	-	-	pF
C _{S(ON)}	ON-state capacitance		-	130	-	-	-	-	pF

Low-ohmic single-pole double-throw analog switch

11.1 Test circuits





Low-ohmic single-pole double-throw analog switch

11.2 ON resistance

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 8 to Figure 14.

Symbol	Parameter	Conditions		T _{amb} =	–40 °C to	+85 °C	T_{amb} = -40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	
R _{ON(peak)}	ON resistance (peak)	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA};$ see Figure 7							'
		$V_{CC} = 1.4 \text{ V}$		-	1.6	3.7	-	4.1	Ω
		V _{CC} = 1.65 V		-	1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 \text{ V}$		-	0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 \text{ V}$		-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 \text{ V}$		-	0.5	0.75	-	0.9	Ω
ΔR_{ON}	ON resistance mismatch between channels	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	[2]						
		$V_{CC} = 1.4 \text{ V}$		-	0.04	0.3	-	0.3	Ω
		$V_{CC} = 1.65 \text{ V}$		-	0.04	0.2	-	0.3	Ω
		$V_{CC} = 2.3 \text{ V}$		-	0.02	0.08	-	0.1	Ω
		$V_{CC} = 2.7 \text{ V}$		-	0.02	0.075	-	0.1	Ω
		$V_{CC} = 4.3 \text{ V}$		-	0.02	0.075	-	0.1	Ω
R _{ON(flat)}	ON resistance (flatness)	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	[3]						
		$V_{CC} = 1.4 \text{ V}$		-	1.0	3.3	-	3.6	Ω
		$V_{CC} = 1.65 \text{ V}$		-	0.5	1.2	-	1.3	Ω
		$V_{CC} = 2.3 \text{ V}$		-	0.15	0.3	-	0.35	Ω
		$V_{CC} = 2.7 \text{ V}$		-	0.13	0.3	-	0.35	Ω
		$V_{CC} = 4.3 \text{ V}$		-	0.2	0.4	-	0.45	Ω

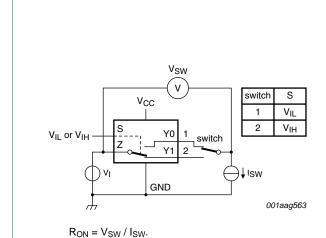
^[1] Typical values are measured at T_{amb} = 25 °C.

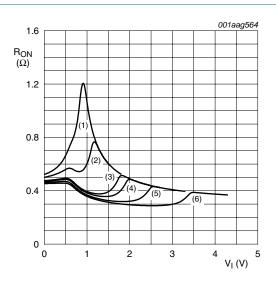
^[2] Measured at identical V_{CC} , temperature and input voltage.

^[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

Low-ohmic single-pole double-throw analog switch

11.3 ON resistance test circuit and graphs



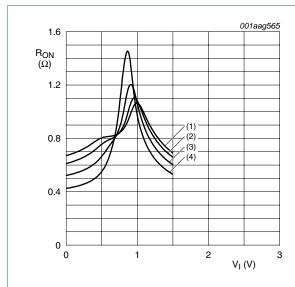


- (1) $V_{CC} = 1.5 \text{ V}.$
- (2) $V_{CC} = 1.8 \text{ V}.$
- (3) $V_{CC} = 2.5 \text{ V}.$
- (4) $V_{CC} = 2.7 \text{ V}.$
- (5) $V_{CC} = 3.3 \text{ V}.$
- (6) $V_{CC} = 4.3 \text{ V}$. Measured at $T_{amb} = 25 \,^{\circ}\text{C}$.

Fig 7. Test circuit for measuring ON resistance

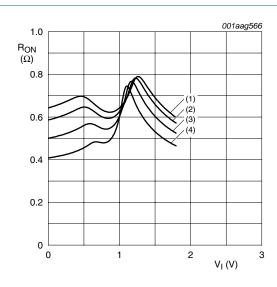
Fig 8. Typical ON resistance as a function of input voltage

Low-ohmic single-pole double-throw analog switch



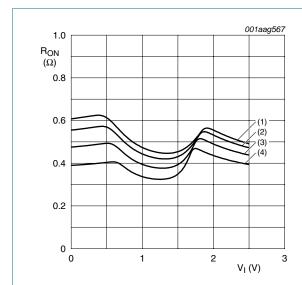
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 9. ON resistance as a function of input voltage; $V_{CC} = 1.5 \text{ V}$



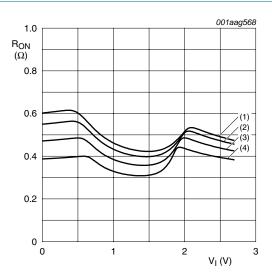
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 10. ON resistance as a function of input voltage; $V_{CC} = 1.8 \text{ V}$



- (1) $T_{amb} = 125 \, ^{\circ}C.$
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 11. ON resistance as a function of input voltage; $V_{CC} = 2.5 \text{ V}$

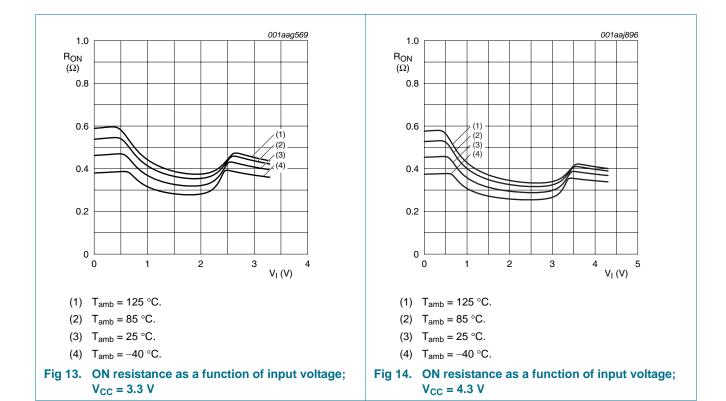


- (1) $T_{amb} = 125 \,^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 12. ON resistance as a function of input voltage; $V_{CC} = 2.7 \text{ V}$

NX3L1G3157

Low-ohmic single-pole double-throw analog switch



12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

Symbol Parameter		Conditions	Ta	_{mb} = 25	°C	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$			Unit
				Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{en}	enable time	S to Z or Yn; see Figure 15							
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	28	43	-	48	52	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	23	35	-	38	42	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	17	27	-	29	32	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	14	25	-	27	30	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	14	25	-	27	30	ns
t _{dis}	disable time	S to Z or Yn; see Figure 15							
		$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	9	20	-	25	30	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	6	15	-	20	23	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	5	11	-	14	16	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	4	10	-	12	14	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	4	10	-	12	14	ns

Low-ohmic single-pole double-throw analog switch

 Table 9.
 Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 17.

Symbol	Parameter	Conditions	Ta	T _{amb} = 25 °C		T _{amb} =	Unit		
			Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{b-m} break-before-make	see Figure 16 [2]								
	time	$V_{CC} = 1.4 \text{ V to } 1.6 \text{ V}$	-	19	-	4	-	-	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	-	17	-	4	-	-	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	-	13	-	2	-	-	ns
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	10	-	2	-	-	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	10	-	2	-	-	ns

^[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

12.1 Waveform and test circuits

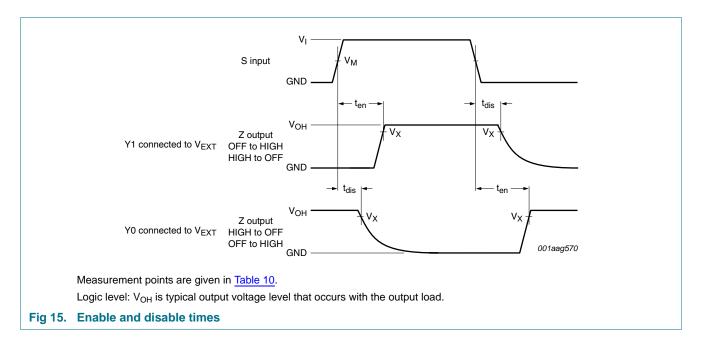
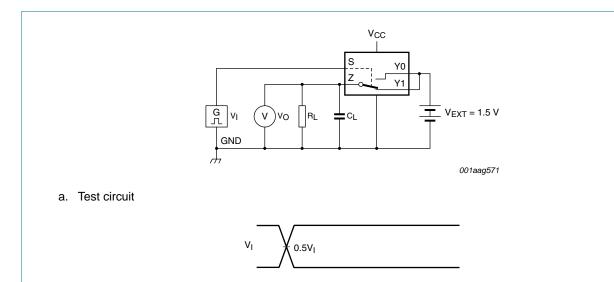


Table 10. Measurement points

Supply voltage	Input	Output
V _{CC}	V _M	V _X
1.4 V to 4.3 V	0.5V _{CC}	0.9V _{OH}

^[2] Break-before-make guaranteed by design.

Low-ohmic single-pole double-throw analog switch



V_O 0.9V_O 0

b. Input and output measurement points

Fig 16. Test circuit for measuring break-before-make timing

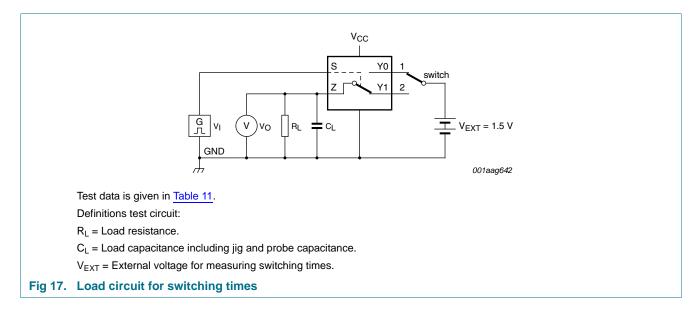


Table 11. Test data

Supply voltage	Input		Load	
V _{CC}	V _I	t _r , t _f	CL	R _L
1.4 V to 4.3 V	V _{CC}	≤ 2.5 ns	35 pF	50 Ω

Low-ohmic single-pole double-throw analog switch

12.2 Additional dynamic characteristics

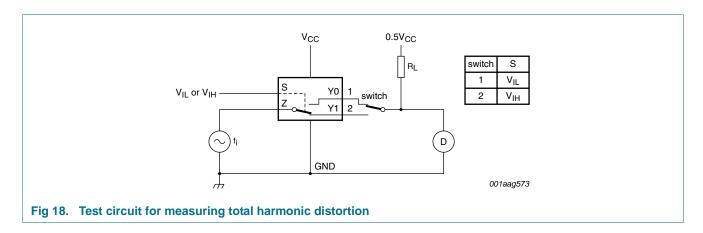
Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = \text{GND}$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns; $T_{amb} = 25$ °C.

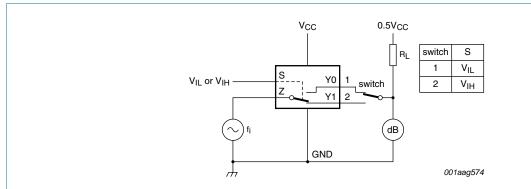
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	total harmonic distortion	f_i = 20 Hz to 20 kHz; R_L = 32 Ω ; see Figure 18	<u>[1]</u>			
		$V_{CC} = 1.4 \text{ V}; V_I = 1 \text{ V (p-p)}$	-	0.15	-	%
		$V_{CC} = 1.65 \text{ V}; V_I = 1.2 \text{ V (p-p)}$	-	0.10	-	%
		$V_{CC} = 2.3 \text{ V}; V_{I} = 1.5 \text{ V (p-p)}$	-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}; V_{I} = 2 \text{ V (p-p)}$	-	0.02	-	%
		$V_{CC} = 4.3 \text{ V}; V_{I} = 2 \text{ V (p-p)}$	-	0.02	-	%
f _(-3dB)	–3 dB frequency response	$R_L = 50 \Omega$; see Figure 19	[1]			
		V _{CC} = 1.4 V to 4.3 V	-	60	-	MHz
α_{iso}	isolation (OFF-state)	f_i = 100 kHz; R_L = 50 Ω ; see Figure 20	[1]			
		V _{CC} = 1.4 V to 4.3 V	-	-90	-	dB
V _{ct}	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 21				
		V _{CC} = 1.4 V to 3.6 V	-	0.2	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	0.3	-	V
Q _{inj}	charge injection	f_i = 1 MHz; C_L = 0.1 nF; R_L = 1 M Ω ; V_{gen} = 0 V; R_{gen} = 0 Ω ; see Figure 22				
		V _{CC} = 1.5 V	-	3	-	рС
		V _{CC} = 1.8 V	-	4	-	рС
		V _{CC} = 2.5 V	-	6	-	рС
		$V_{CC} = 3.3 \text{ V}$	-	9	-	рС
		$V_{CC} = 4.3 \text{ V}$	-	15	-	рС

^[1] f_i is biased at $0.5V_{CC}$.

12.3 Test circuits



Low-ohmic single-pole double-throw analog switch



Adjust f_i voltage to obtain 0 dBm level at output. Increase f_i frequency until dB meter reads -3 dB.

Fig 19. Test circuit for measuring the frequency response when channel is in ON-state

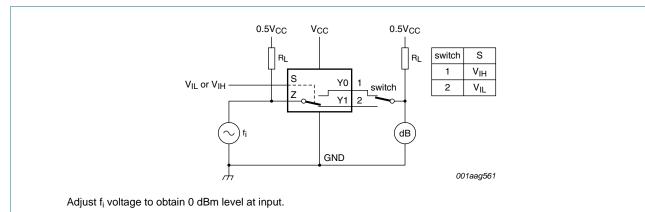
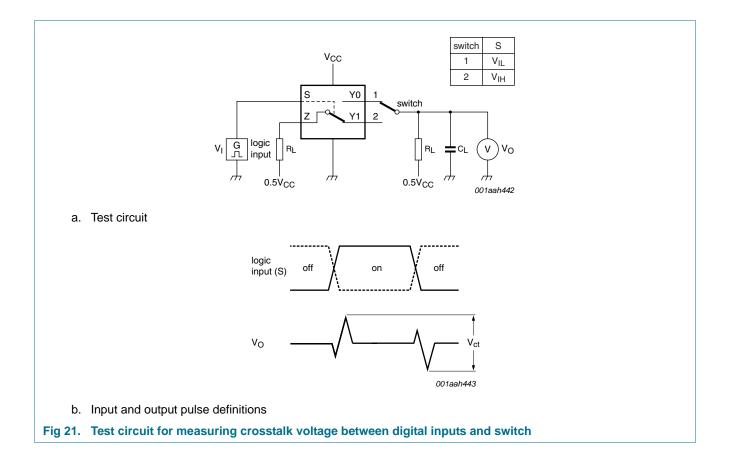
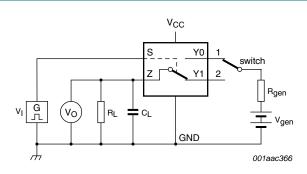


Fig 20. Test circuit for measuring isolation (OFF-state)

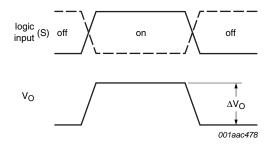
Low-ohmic single-pole double-throw analog switch



Low-ohmic single-pole double-throw analog switch



a. Test circuit



b. Input and output pulse definitions

Definition: $Q_{inj} = \Delta V_O \times C_L$.

 ΔV_{O} = output voltage variation.

R_{gen} = generator resistance.

 V_{gen} = generator voltage.

Fig 22. Test circuit for measuring charge injection

13. Package outline

Plastic surface-mounted package; 6 leads **SOT363** Α X = v M A H_{E} Q ⊕ w M B е detail X **DIMENSIONS (mm are the original dimensions)** Α1 UNIT Α D Е С Q v е e₁ HΕ Lp w у max 2.2 1.8 0.30 0.25 1.35 0.45 0.25 1.1 2.2 0.65 1.3 0.1 0.20 0.10 8.0 1.15 0.15 0.15 **REFERENCES EUROPEAN** OUTLINE ISSUE DATE VERSION **PROJECTION** JEDEC IEC **JEITA**

Fig 23. Package outline SOT363 (SC-88)

NX3L1G3157_8 All information provided in this document is subject to legal disclaimers.

© NXP B.V. 2010. All rights reserved.

04-11-08

06-03-16

SOT363

SC-88

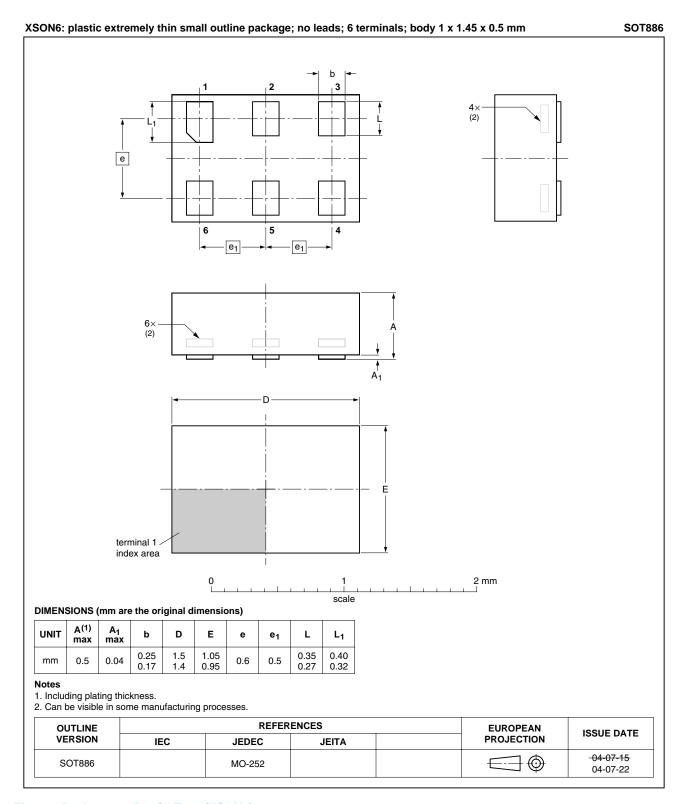


Fig 24. Package outline SOT886 (XSON6)

All information provided in this document is subject to legal disclaimers.

© NXP B.V. 2010. All rights reserved.

Low-ohmic single-pole double-throw analog switch

14. Abbreviations

Table 13. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
PDA	Personal Digital Assistant
TTL	Transistor-Transistor Logic

15. Revision history

Table 14. Revision history

	•			
Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L1G3157_8	20100426	Product data sheet	-	NX3L1G3157_7
Modifications:	• <u>Table 8</u> : ON I	esistance mismatch between	channels changed at '	$V_{CC} = 4.3 \text{ V}.$
NX3L1G3157_7	20100324	Product data sheet	-	NX3L1G3157_6
NX3L1G3157_6	20100208	Product data sheet	-	NX3L1G3157_5
NX3L1G3157_5	20090407	Product data sheet	-	NX3L1G3157_4
NX3L1G3157_4	20080730	Product data sheet	-	NX3L1G3157_3
NX3L1G3157_3	20080721	Product data sheet	-	NX3L1G3157_2
NX3L1G3157_2	20080415	Product data sheet	-	NX3L1G3157_1
NX3L1G3157_1	20071008	Product data sheet	-	-

Low-ohmic single-pole double-throw analog switch

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

16.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Product specification — The information and data provided in a Product data sheet shall define the specification of the product as agreed between NXP Semiconductors and its customer, unless NXP Semiconductors and customer have explicitly agreed otherwise in writing. In no event however, shall an agreement be valid in which the NXP Semiconductors product is deemed to offer functions and qualities beyond those described in the Product data sheet.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

16.3 Disclaimers

Limited warranty and liability — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

In no event shall NXP Semiconductors be liable for any indirect, incidental, punitive, special or consequential damages (including - without limitation - lost profits, lost savings, business interruption, costs related to the removal or replacement of any products or rework charges) whether or not such damages are based on tort (including negligence), warranty, breach of contract or any other legal theory.

Notwithstanding any damages that customer might incur for any reason whatsoever, NXP Semiconductors' aggregate and cumulative liability towards customer for the products described herein shall be limited in accordance with the *Terms and conditions of commercial sale* of NXP Semiconductors.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use in automotive applications — This NXP Semiconductors product has been qualified for use in automotive applications. The product is not designed, authorized or warranted to be

suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

NXP Semiconductors does not accept any liability related to any default, damage, costs or problem which is based on a weakness or default in the customer application/use or the application/use of customer's third party customer(s) (hereinafter both referred to as "Application"). It is customer's sole responsibility to check whether the NXP Semiconductors product is suitable and fit for the Application planned. Customer has to do all necessary testing for the Application in order to avoid a default of the Application and the product. NXP Semiconductors does not accept any liability in this respect.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) will cause permanent damage to the device. Limiting values are stress ratings only and (proper) operation of the device at these or any other conditions above those given in the Recommended operating conditions section (if present) or the Characteristics sections of this document is not warranted. Constant or repeated exposure to limiting values will permanently and irreversibly affect the quality and reliability of the device.

Terms and conditions of commercial sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, unless otherwise agreed in a valid written individual agreement. In case an individual agreement is concluded only the terms and conditions of the respective agreement shall apply. NXP Semiconductors hereby expressly objects to applying the customer's general terms and conditions with regard to the purchase of NXP Semiconductors products by customer.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

16.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

NX3L1G3157_8

All information provided in this document is subject to legal disclaimers.

© NXP B.V. 2010. All rights reserved.

Low-ohmic single-pole double-throw analog switch

17. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

NX3L1G3157

Low-ohmic single-pole double-throw analog switch

18. Contents

NXP Semiconductors

1	General description	1
2	Features and benefits	1
3	Applications	2
4	Ordering information	
5	Marking	2
6	Functional diagram	2
7	Pinning information	3
7.1	Pinning	
7.2	Pin description	
8	Functional description	3
9	Limiting values	4
10	Recommended operating conditions	4
11	Static characteristics	5
11.1	Test circuits	6
11.2	ON resistance	7
11.3	ON resistance test circuit and graphs	8
12	Dynamic characteristics	10
12.1	Waveform and test circuits	11
12.2	Additional dynamic characteristics	13
12.3	Test circuits	13
13	Package outline	17
14	Abbreviations	19
15	Revision history	19
16	Legal information	20
16.1	Data sheet status	20
16.2	Definitions	20
16.3	Disclaimers	20
16.4	Trademarks	20
17	Contact information	21
18	Contents	22

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.